

## MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V <sub>DS</sub>	Drain to Source Voltage			40	V
V <sub>GS</sub>	Gate to Source Voltage			±20	V
I <sub>D</sub>	Drain Current -Continuous			18	^
	-Pulsed			Α	
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 3)			541	mJ
P <sub>D</sub>	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	2.5	W
	Power Dissipation $T_A = 25 \text{ °C}$ (Note 1b)		(Note 1b)	1	VV
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C

## **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Note 1)	25	°C ///
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	°C/W

## Package Marking and Ordering Information

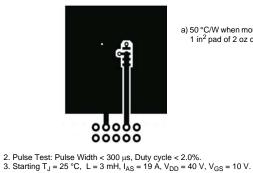
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS8638	FDS8638	SO-8	13 "	12 mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V	40			V	
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		32		mV/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 32 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA	
On Chara	cteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.0	1.9	3.0	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-7		mV/°C	
	Static Drain to Source On Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 18 A		3.3	4.3		
r <sub>DS(on)</sub>		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 16 A		4.0	5.4	mΩ	
		$V_{GS}$ = 10 V, $I_{D}$ = 18 A, $T_{J}$ = 125 °C		4.8	6.3		
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 5 V, I_{D} = 18 A$		88		S	
Dynamic	Characteristics						
C <sub>iss</sub>	Input Capacitance			4270	5680	pF	
C <sub>oss</sub>	Output Capacitance	── V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, ── f = 1 MHz		1175	1560	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance			120	180	pF	
R <sub>g</sub>	Gate Resistance			0.9		Ω	
Switching	g Characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time			16	30	ns	
t <sub>r</sub>	Rise Time	$V_{DD} = 20 \text{ V}, \text{ I}_{D} = 18 \text{ A},$		6	13	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time	$-V_{GS}$ = 10 V, R <sub>GEN</sub> = 6 $\Omega$		39	63	ns	
t <sub>f</sub>	Fall Time			5	10	ns	
Qg	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		61	86	nC	
Qg	Total Gate Charge	$ \begin{array}{c} V_{GS} = 0 \ V \ to \ 10 \ V \\ V_{GS} = 0 \ V \ to \ 4.5 \ V \\ I_D = 18 \ A \end{array} \\ \end{array} $		27	39	nC	
Q <sub>gs</sub>	Gate to Source Charge	ID = 18 A		12		nC	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			7.2		nC	

V <sub>SD</sub> Source to Drain	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 18 A$	(Note 2)	0.81	1.3	V
	Source to Drain Diode Polward voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{S} = 2.1 \text{ A}$	(Note 2)	0.71	1.2	v
t <sub>rr</sub>	Reverse Recovery Time	-I <sub>F</sub> = 18 A, di/dt = 100 A/μs		51	82	ns
Q <sub>rr</sub>	Reverse Recovery Charge	$-1_{\rm F} = 10$ A, $u/u_{\rm I} = 100$ A/ $\mu_{\rm S}$	<b>)</b>	30	49	nC

NOTES:

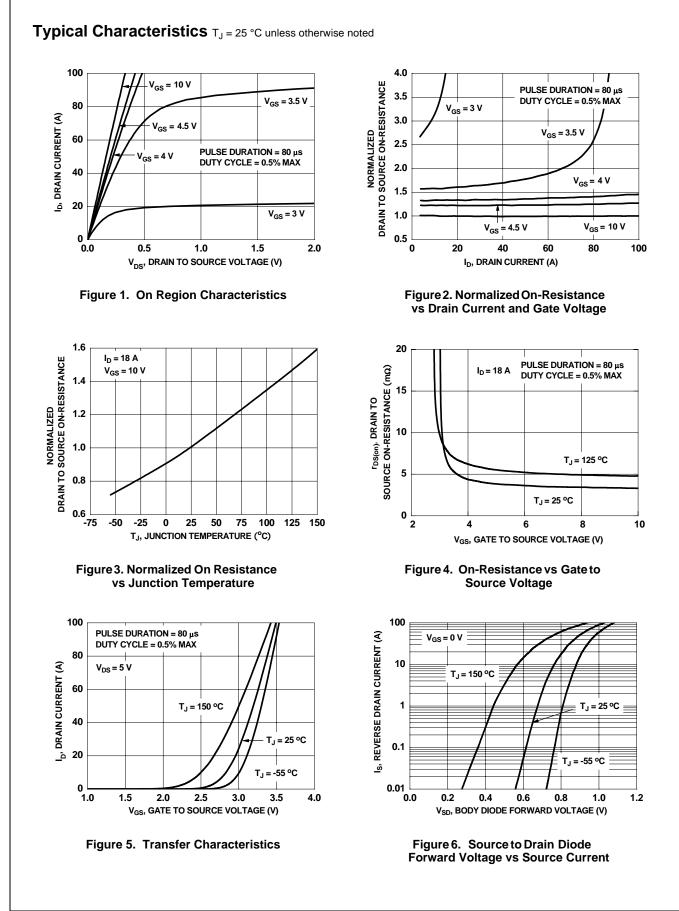
1.  $R_{\theta JA}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



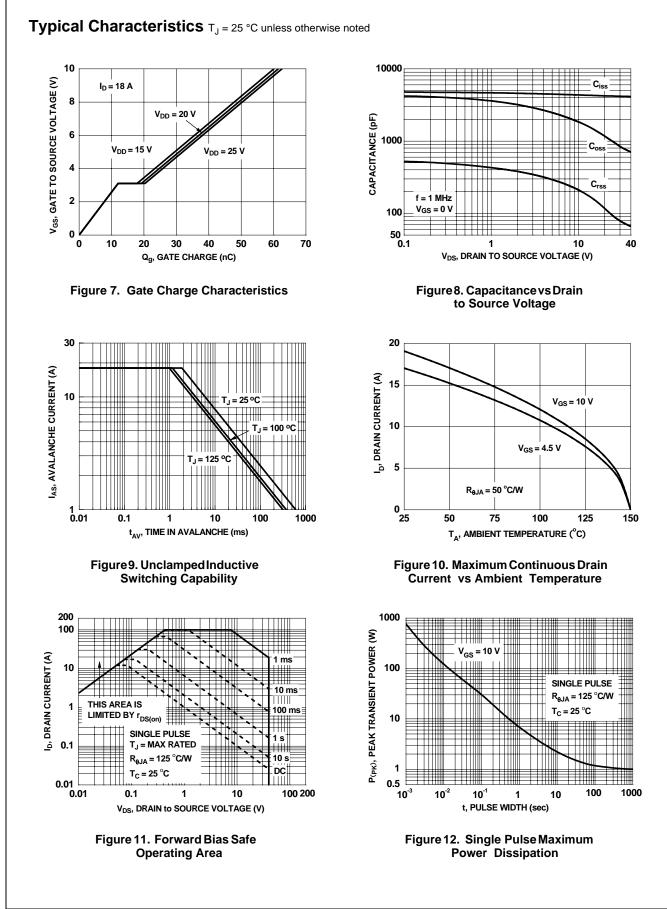
a) 50 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.

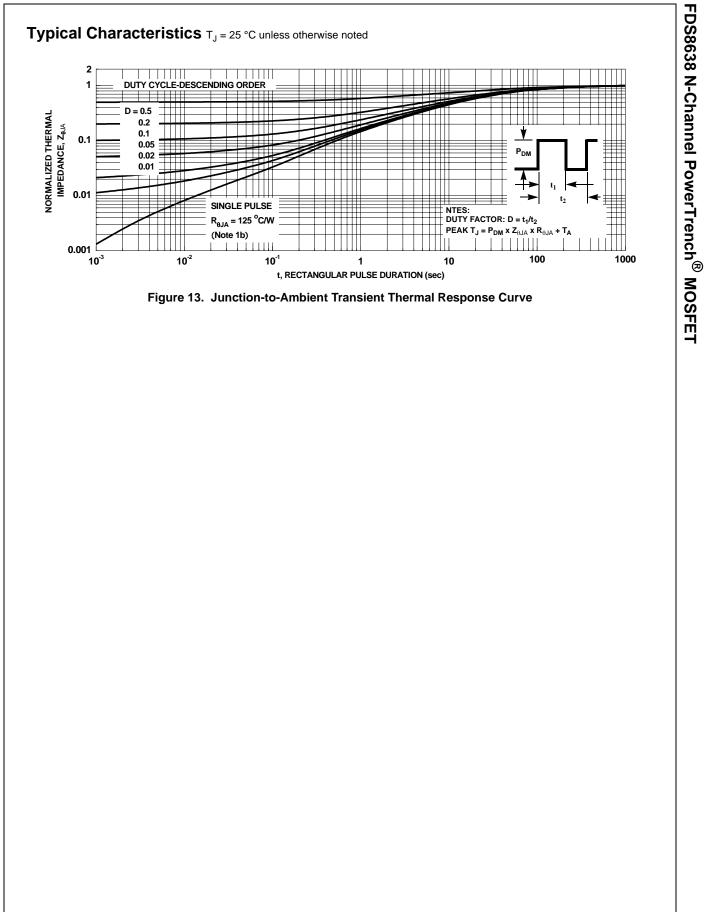


b) 125 °C/W when mounted on a minimum pad.











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